



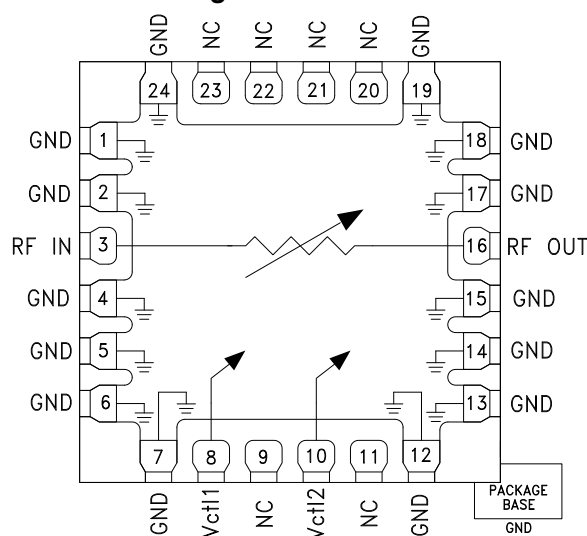
GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

Typical Applications

The HMC985LP4KE is ideal for:

- Point-to-Point Radio
- VSAT Radio
- Test Instrumentation
- Microwave Sensors
- Military, ECM & Radar

Functional Diagram



Features

- Wide Bandwidth: 10 - 40 GHz
- Excellent Linearity: +32 dB Input IP3
- Wide Attenuation Range: 35 dB
- No External Matching
- 24 Lead 4x4 mm SMT Package: 16 mm²

General Description

The HMC985LP4KE is an absorptive Voltage Variable Attenuator (VVA) which operates from 10 - 40 GHz and is ideal in designs where an analog DC control signal must be used to control RF signal levels over a 35 dB dynamic range. It features two shunt-type attenuators which are controlled by two analog voltages, Vctl1 and Vctl2. Optimum linearity performance of the attenuator is achieved by first varying Vctl1 of the first attenuation stage from -3V to 0V with Vctl2 fixed at -3V. The control voltage of the second attenuation stage, Vctl2, should then be varied from -3V to 0V with Vctl1 fixed at 0V.

if the Vctl1 and Vctl2 pins are connected together it is possible to achieve the full analog attenuation range with only a small degradation in input IP3 performance. Applications include AGC circuits and temperature compensation of multiple gain stages in microwave point-to-point and VSAT radios.

Electrical Specifications, $T_A = +25^\circ\text{C}$, Test Condition $V_{ctl1} = V_{ctl2}$

| Parameter | Frequency | Min. | Typ. | Max. | Units |
|---|-------------|------|------|------|-------|
| Insertion Loss ^[1] | 10 - 20 GHz | | 3 | 3.5 | dB |
| | 20 - 30 GHz | | 3 | 4 | dB |
| | 30 - 40 GHz | | 3.5 | 4.5 | dB |
| Attenuation Range | 10 - 20 GHz | 25 | 30 | | dB |
| | 20 - 30 GHz | 30 | 35 | | dB |
| | 30 - 40 GHz | 35 | 40 | | dB |
| Input Return Loss | 10 - 40 GHz | | 13 | | dB |
| Output Return Loss | 10 - 40 GHz | | 13 | | dB |
| Input Third Order Intercept (two-tone input Power = 10 dBm Each Tone) ^[2] | | | 33 | | dBm |

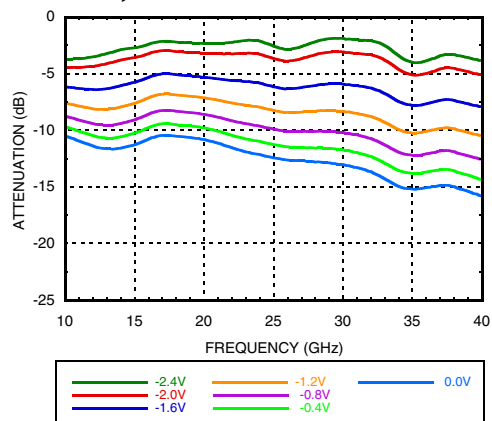
[1] Vctl1 = Vctl2 = -2.4V

[2] Vctl1 = Vctl2 = -2.0V worst case

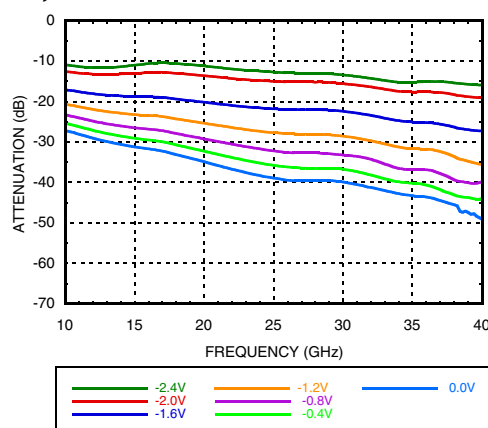


GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

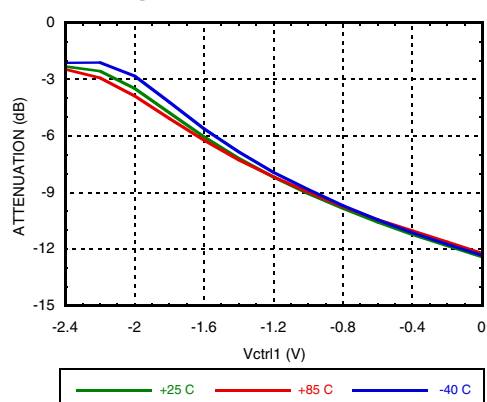
Attenuation vs. Frequency over V_{ctrl1} = Variable, $V_{ctrl2} = -3V$



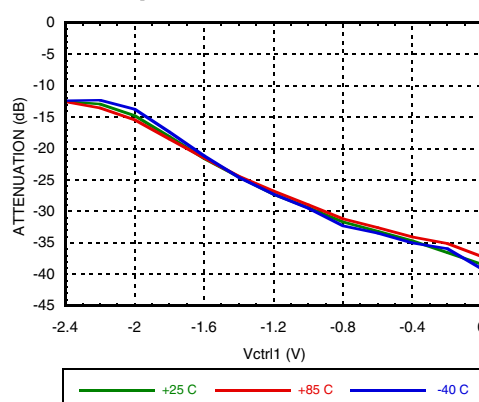
Attenuation vs. Frequency over $V_{ctrl1} = 0V$, V_{ctrl2} = Variable



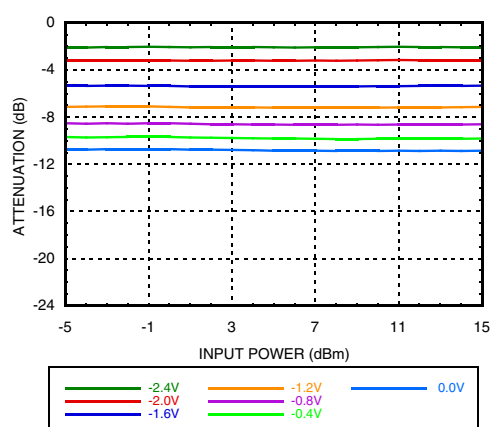
Attenuation vs. V_{ctrl1} Over Temperature @ 25 GHz, $V_{ctrl2} = -3V$



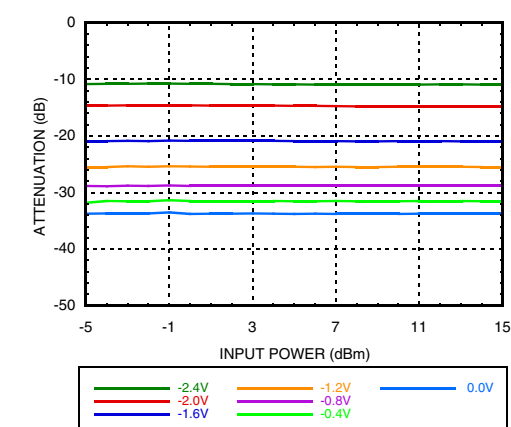
Attenuation vs. V_{ctrl2} Over Temperature @ 30 GHz, $V_{ctrl1} = 0V$



Attenuation vs. P_{in} @ 20 GHz over V_{ctrl1} V_{ctrl1} = Variable, $V_{ctrl2} = -3V$



Attenuation vs. P_{in} @ 20 GHz over V_{ctrl2} V_{ctrl2} = Variable, $V_{ctrl1} = 0V$

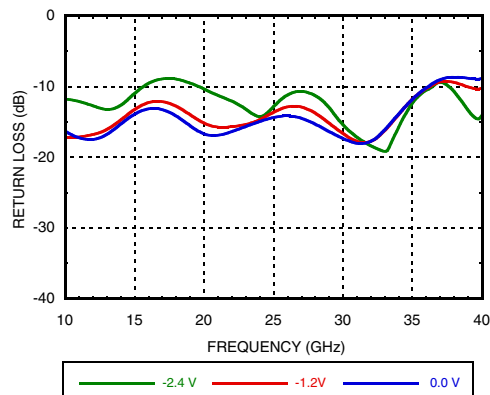




GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

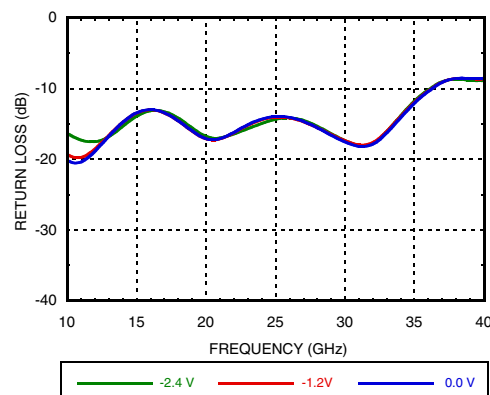
Input Return Loss

Vctl1 = Variable, Vctl2 = -3V



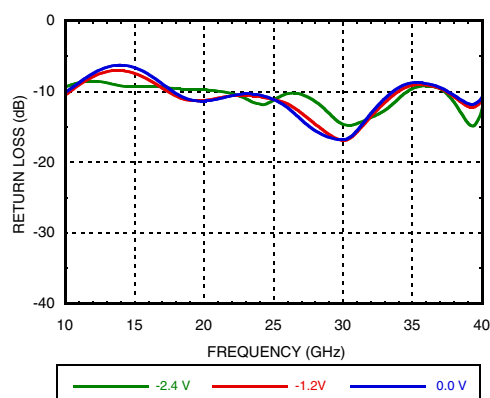
Input Return Loss

Vctl1 = 0V, Vctl2 = Variable



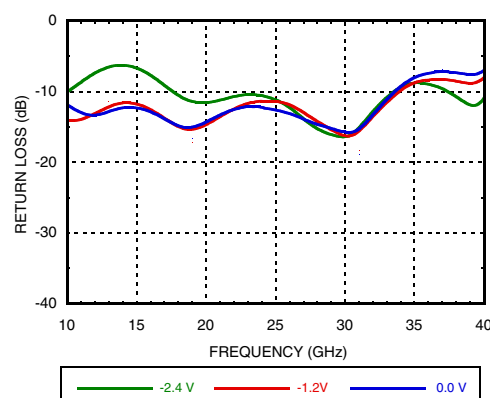
Output Return Loss

Vctl1 = Variable, Vctl2 = -3V



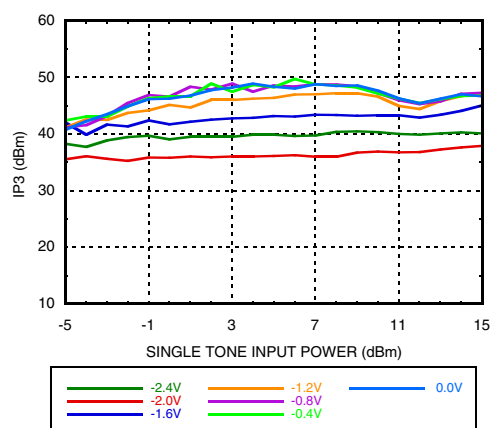
Output Return Loss

Vctl1 = 0V, Vctl2 = Variable



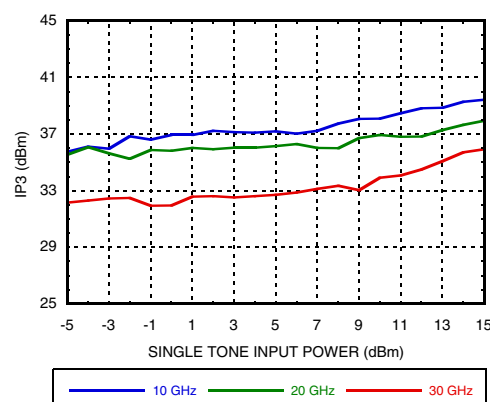
Input IP3 vs. Input Power @ 20 GHz

Vctl1 = Variable, Vctl2 = -3V



Input IP3 vs. Input Power Over Frequency

Vctl1 = -2V, Vctl2 = -3V [1]

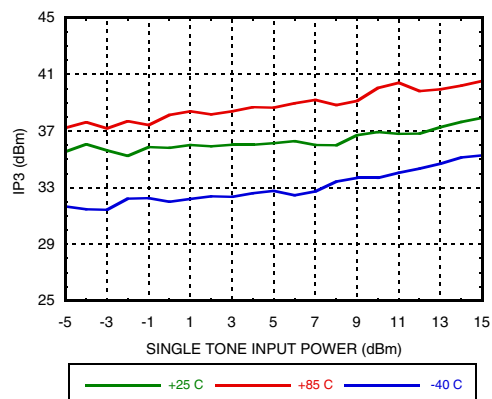


[1] Worst Case IP3

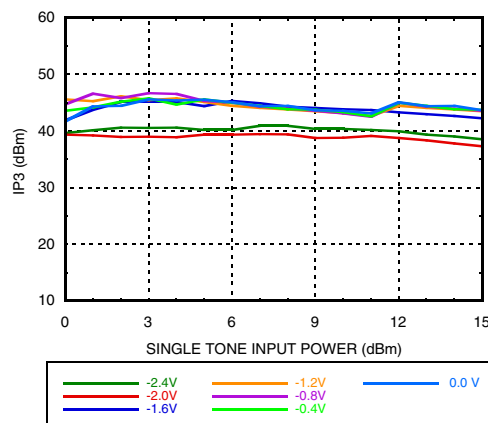


GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

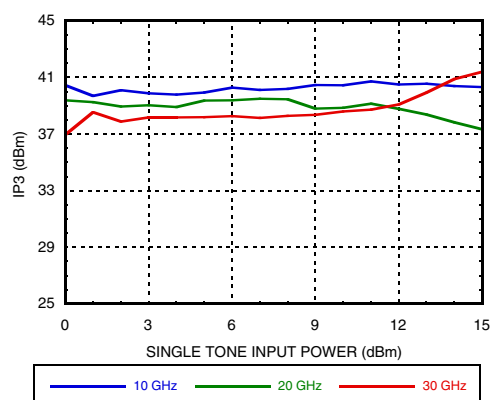
**Input IP3 vs. Input Power Over Temperature
@ 20 GHz, Vctl1 = -2V, Vctl2 = -3V [1]**



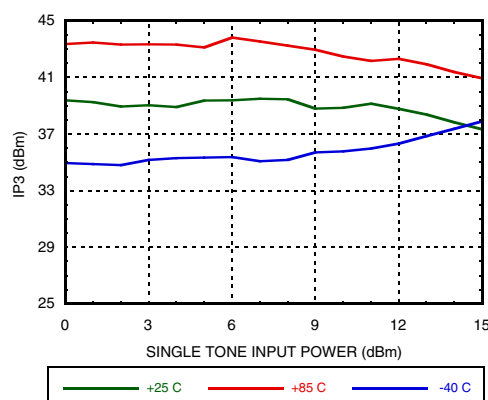
**Input IP3 vs. Input Power @ 20 GHz
Vctl2 = Variable, Vctl1 = 0V**



**Input IP3 vs. Input Power Over Frequency
Vctl2 = -2V, Vctl1 = 0V [1]**



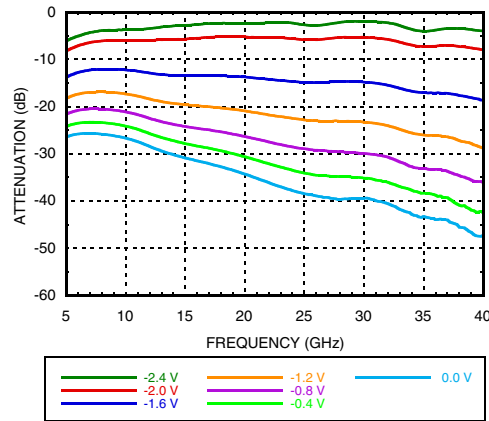
**Input IP3 vs Input Power over Temperature
@ 20 GHz, Vctl2 = -2V, Vctl1 = 0V [1]**



[1] Worst Case IP3

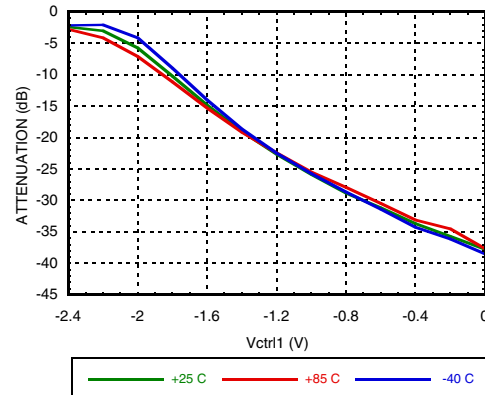


Attenuation vs Frequency Over Vctrl
Vctrl1 = Vctrl2

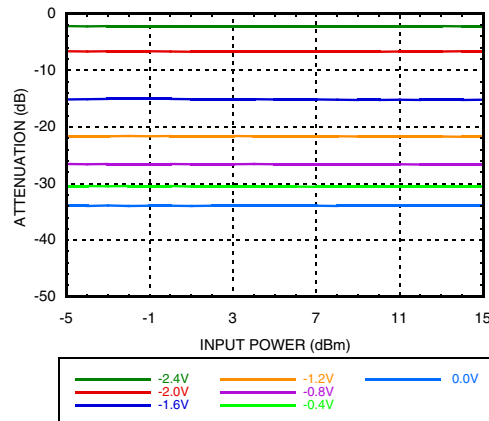


**GaAs MMIC VOLTAGE - VARIABLE
ATTENUATOR, 10 - 40 GHz**

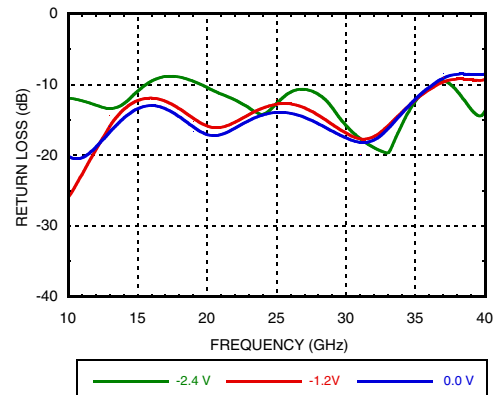
Attenuation vs. Vctrl Over Temperature
@ 20 GHz, Vctrl1 = Vctrl2



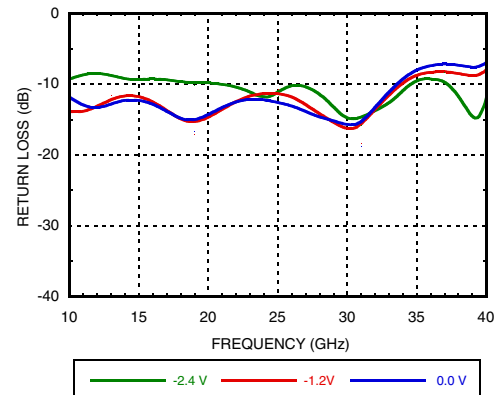
Attenuation vs. Pin @ 20 GHz Over Vctrl
Vctrl1 = Vctrl2



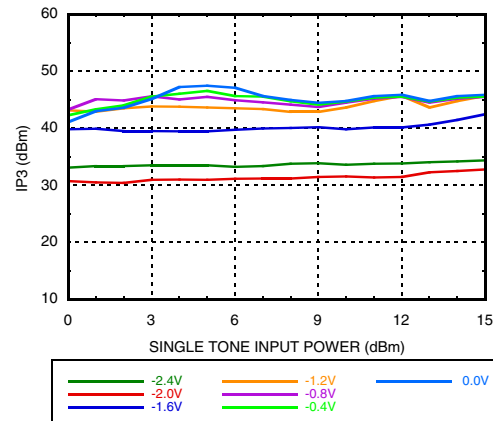
Input Return Loss, Vctrl1 = Vctrl2



Output Return Loss, Vctrl1 = Vctrl2

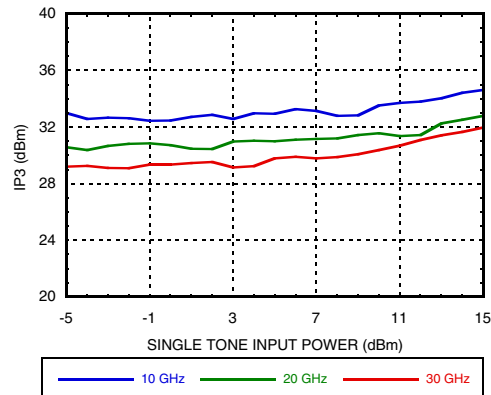


Input IP3 vs. Input Power Over Vctrl @ 20 GHz, Vctrl1 = Vctrl2



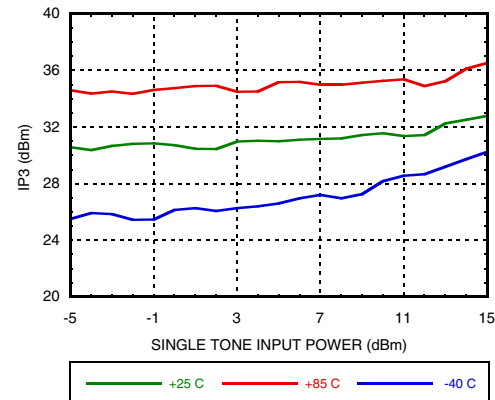


Input IP3 vs. Input Power Over Frequency
Vctl1 = Vctl2



**GaAs MMIC VOLTAGE - VARIABLE
ATTENUATOR, 10 - 40 GHz**

**Input IP3 vs. Input Power Over
Temperature @ 20 GHz Vctl1 = Vctl2**

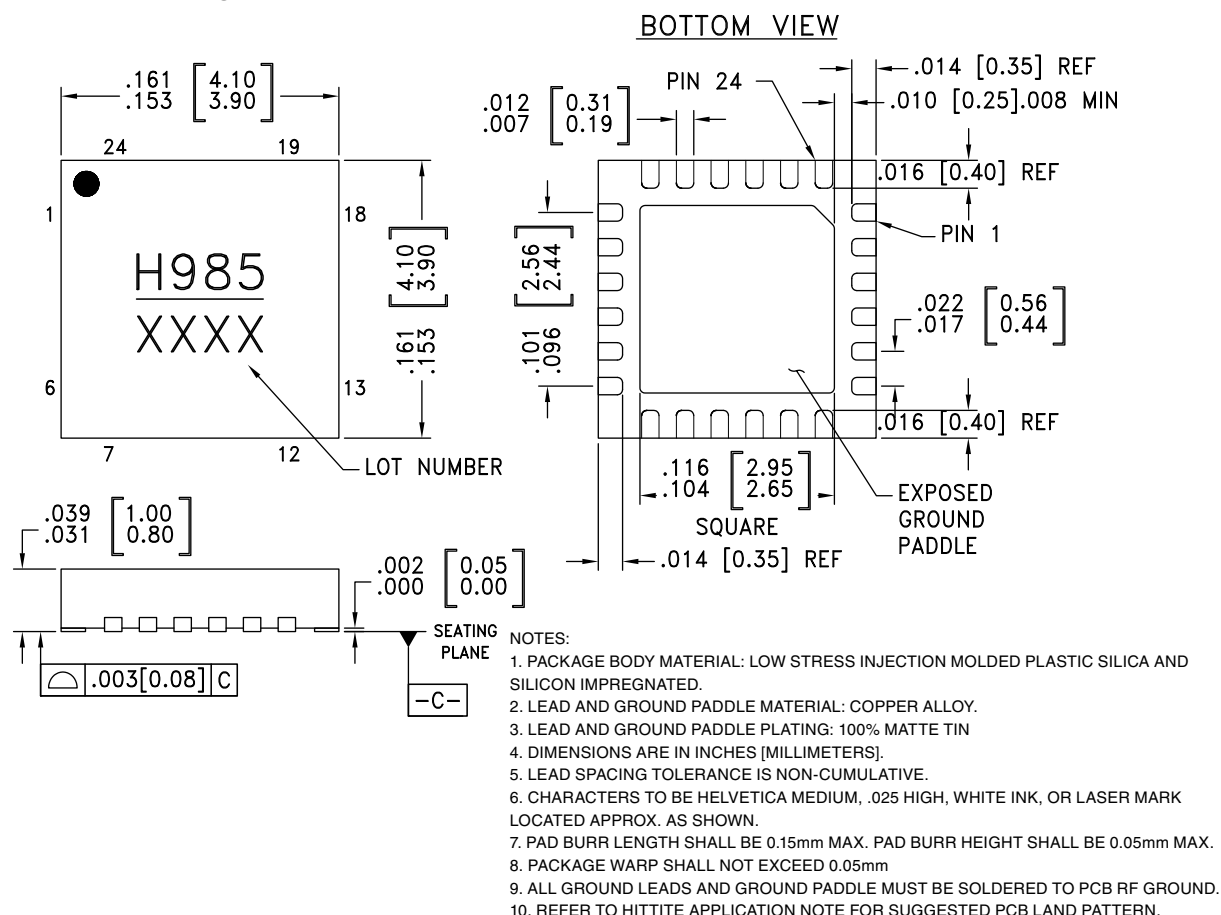



**GaAs MMIC VOLTAGE - VARIABLE
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Absolute Maximum Ratings

| | |
|--|----------------------|
| Control Voltage | +1 to -5V |
| Input RF Power | 30 dBm |
| Maximum Junction Temperature | 165 °C |
| Thermal Resistance (R_{TH}) (junction to ground paddle) | 62 °C/W |
| Operating Temperature | -40°C to +85°C |
| Storage Temperature | -65°C to 125°C |
| ESD Sensitivity (HBM) | Class1A, passed 250V |



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing

Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking |
|-------------|--|---------------|---------------------|-----------------|
| HMC985LP4KE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 ^[1] | H985 XXX |


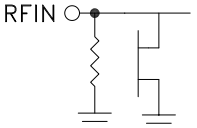
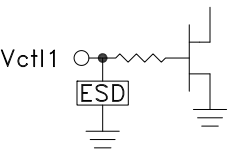
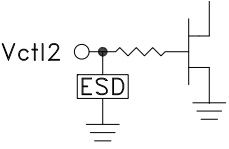
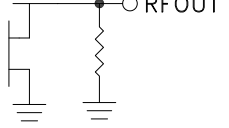
[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

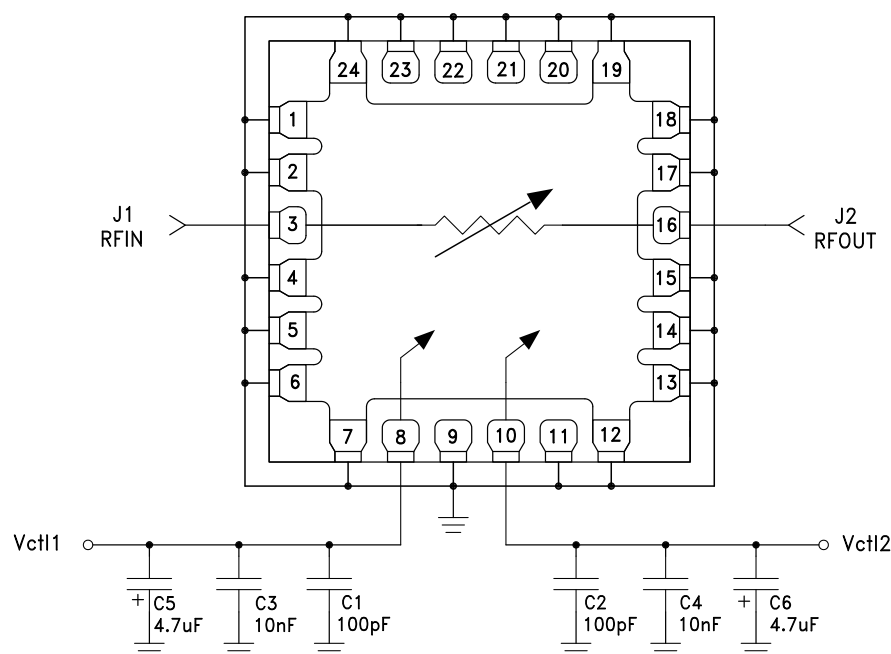


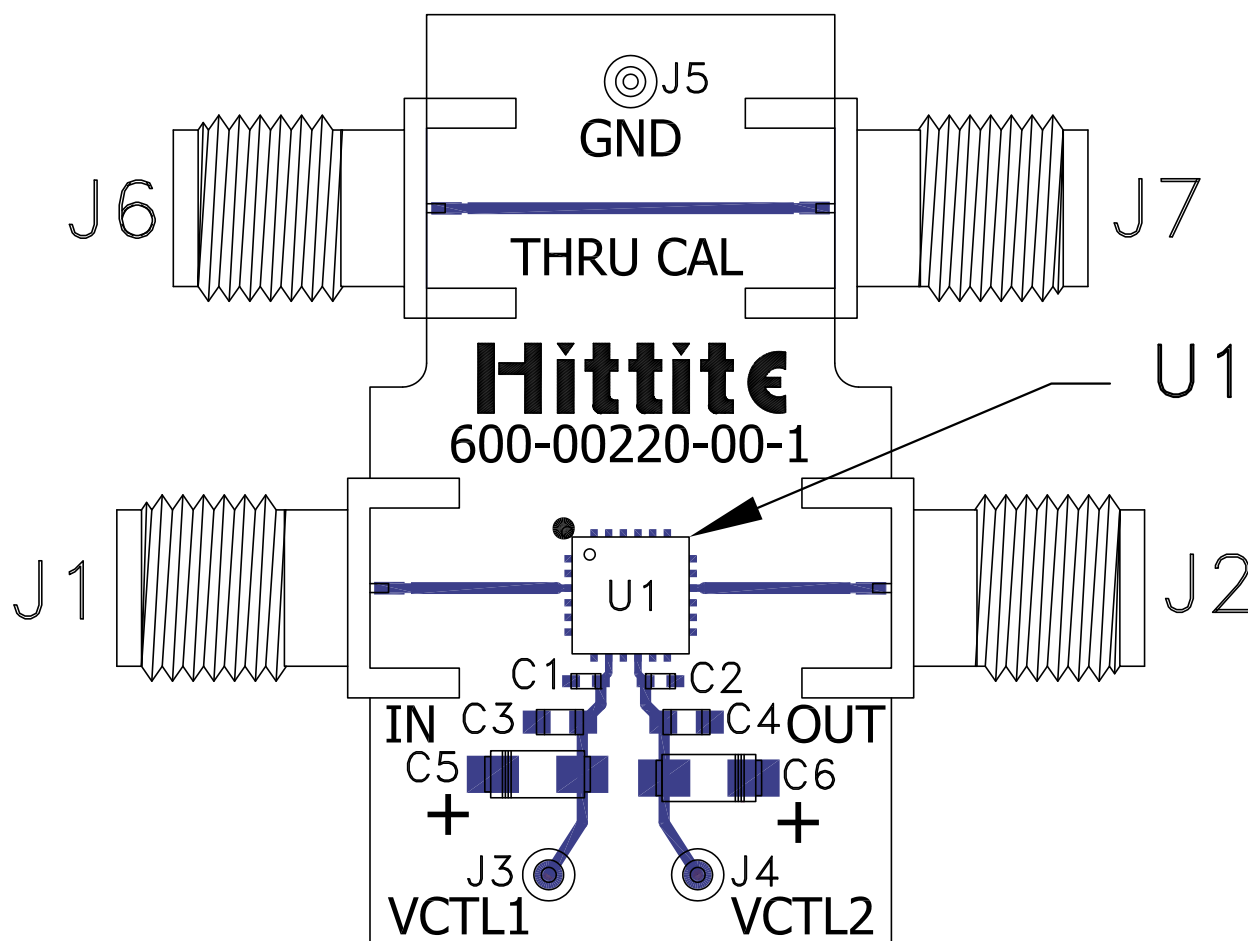
GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

Pin Descriptions

| Pin Number | Function | Description | Pin Schematic |
|-----------------------------|----------|---|---|
| 1, 2, 4-7, 12-15, 17-19, 24 | GND | These pins and package bottom must be connected to RF/DC ground externally. |  |
| 3 | RFIN | This pad is DC coupled and matched to 50 Ohms. |  |
| 8 | Vctl1 | Control Voltage 1. |  |
| 9, 11, 20-23 | NC | These pins are not connected internally, however all data shown herein was measured with these pins connected to RF/DC ground externally. | |
| 10 | Vctl2 | Control Voltage 2. |  |
| 16 | RFOUT | This pad is DC coupled and matched to 50 Ohms. |  |

Application Circuit




**GaAs MMIC VOLTAGE - VARIABLE
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Evaluation PCB

List of Materials for Evaluation PCB EVAL01-HMC985LP4KE ^[1]

| Item | Description |
|--------------|-----------------------------------|
| J1-J2, J6-J7 | K Connectors. |
| J3-J5 | DC Pins. |
| C1-C2 | 100pF Capacitors, 0402 Pkg. |
| C3-C4 | 0.01 μ F Capacitor, 0603 Pkg. |
| C5-C6 | 4.7 μ F Case A, Tantalum. |
| U1 | HMC985LP4KE VVA. |
| PCB | 600-00220-00 Evaluation PCB. |

[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

**GaAs MMIC VOLTAGE - VARIABLE
ATTENUATOR, 10 - 40 GHz****Notes:**